

# MULTISPECTRAL PHOTON-COUNTING FOR MEDICAL IMAGING AND BEAM CHARACTERIZATION

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<sup>1</sup>on behalf of the consortium of research groups from HIP, Aalto, LUT and STUK.

# Idea and motivation

For medical imaging we need photon-counting detectors that

- are capable of high radiation fluence rate ( $> 10^8 \text{mm}^{-2}\text{s}^{-1}$ ),
- have good timing resolution,
- have good stopping power,
- good energy discrimination.

Our approach: combining two worlds for something new

- In-house development of detectors using high Z materials.
- Readout technology and expertise from involvement in high energy physics experiments.

# In-house detector development

## History at HIP

- Radiation-hard silicon strip detectors.
- Detectors made of high-resistivity magnetic Czochralski silicon (MCz).
- Silicon strip detectors (n-type) for High Luminosity LHC.
- Defect studies and quality assurance of semiconductor detectors.
- Mechanics and commissioning of the current CMS Tracking detector.

## Modern processing techniques

- Access to Micronova, Centre for Micro and Nanotechnology in Finland.
- Present key technology: Atomic Layer Deposition (ALD).

## Local detector characterization techniques

- Probestations, scanning Transient Current Technique (TCT), IR-imaging and spectroscopy scanner.

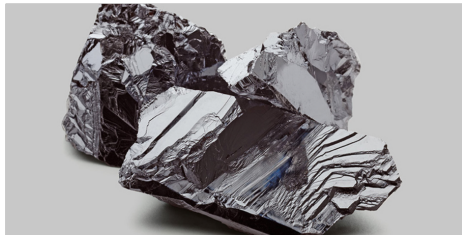
# Cadmium Telluride

## Material

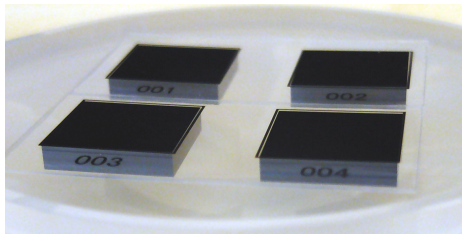
- High stopping power (high Z).
- Usable at room temperatures.
- Wide band gap of 1.44 eV (usable at room temperatures).
- Very brittle, difficult to grow.
- Processing temperatures  $< 150^{\circ}\text{C}$ .
- Not all chemicals from Si processing can be used.

## Crystals

- We use currently CdTe crystals of size  $1 \times 1 \text{ cm}^2$ .
- 1 and 2 mm thickness available.



from [www.5nplus.com/cadmium-telluride.html](http://www.5nplus.com/cadmium-telluride.html)



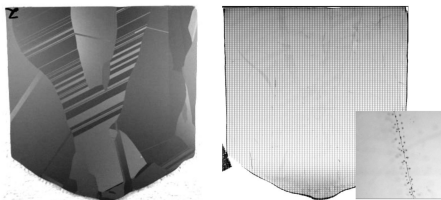


# Quality assurance

## CdTe material

Max. 2 inch ingot available, not fully mono-crystalline. Come with various crystallographic defects that affect detector performance:

- Grain and twin boundaries
- Fractures
- Tellurium inclusions, etc . . .



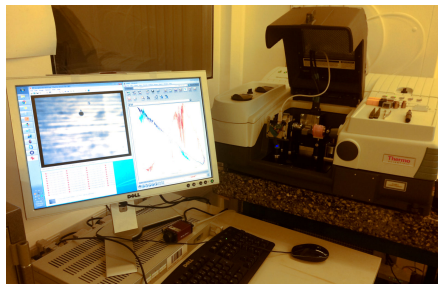
from Szeles et. al., doi:10.1117/12.683552.

## Quality assurance

3D characterization using IR scanning microscope

- Resolution close to  $1\mu\text{m}$  (diffraction limit)
- Spectroscopy possible
- Result (with aid of neural networks):  
Detailed 2/3D maps of defect occurrences.

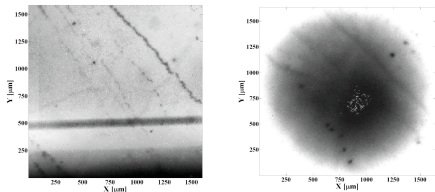
see A. Winkler et al., NIM A 924 (2019) 28



# Quality assurance

## Under investigation

- How do Te inclusions affect locally the charge collection efficiency (CCE)?
- Currently we study CCE using scanning TCT and micro proton beam (IBIC) in collab. with Ruđer Bošković Institute.
- Goal: correlation between local Te inclusions and drop of CCE.



Example of scanning through CdTe crystal

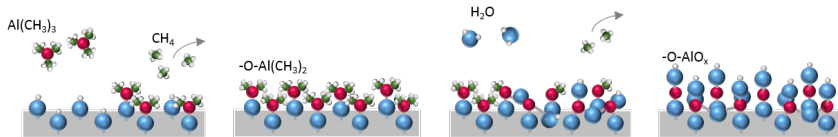
see M. Kalliokoski et al., *IEEE Trans. Nucl. Sci.*, **66**, 5 (2019)

Size:  $200 \times 160 \mu\text{m}$ ;  $15 \mu\text{m}$  step per frame.

# Atomic Layer Deposition

## ALD principle

- Self-terminating gas-solid reactions.
- E.g.: layer by layer growing of  $\text{Al}_2\text{O}_3$  on high-resistivity MCz silicon in Beneq TFS-500 ALD reactor. (presented at VCI conference by Jennifer Ott, paper submitted)

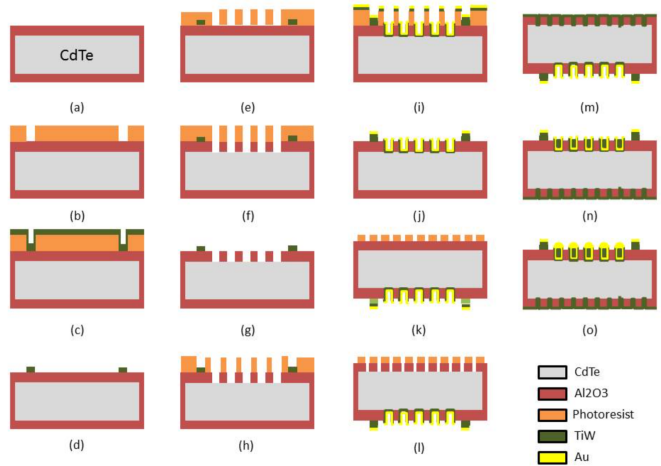


## Details of aluminium oxide growth at $120^\circ\text{C}$

- First  $\text{Al}(\text{CH}_3)_3$  pulse as metal precursor followed by  $\text{N}_2$  purge.
- Next  $\text{H}_2\text{O}$  pulses followed by  $\text{N}_2$  purge.
- Repeating cycles until sufficient layer thickness (here around 90 nm).

# Processing of CdTe pixel sensor

- a) Low temp. ALD of  $\text{Al}_2\text{O}_3$
- b,c,d) Alignment marks (TiW)
- e,f,g) Opening contacts to ALD passivation layer (wet chemical etching)
- h,i) Contact metallization (sputtering of TiW and Au)
- j) Lift-off process
- k,l,m) Backside processing similar to front side with TiW sputtering
- n,o) Electroless Ni growth and Au metallization, UBM



see A. Gädda et al. 2017 JINST 12 C12031

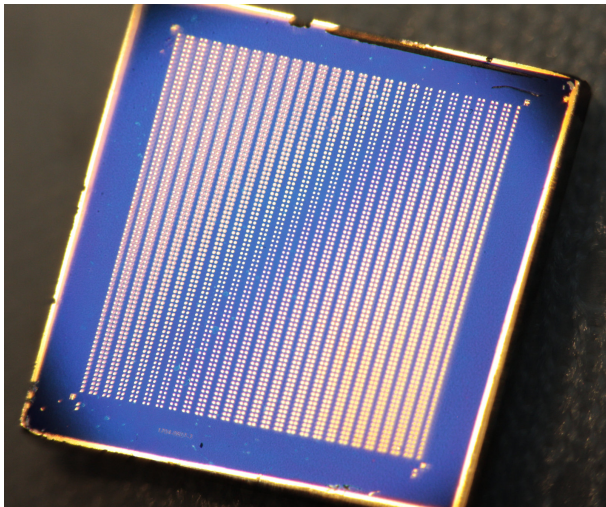
# The CdTe pixel sensor

## Ingredients

- Detector grade CdTe crystal, (111) orientation.
- Resistivity  $> 10^9 \Omega\text{cm}$ .
- Size:  $10 \times 10 \text{ mm}^2$ .
- Thickness 1 mm.

## The ready sensor

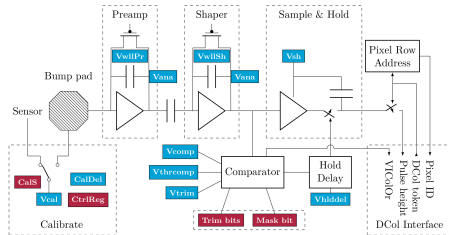
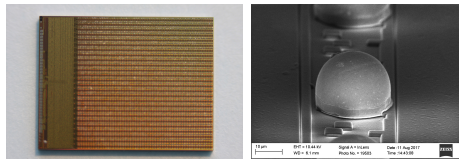
- Schottky type detector.
- $52 \times 80$  pixels in 26 double column pattern.
- Layout matching PSI46 ROC structure.
- Patterned backside



# PSI46dig ROC

## Readout chip for prototypes

- CMOS ASIC developed by PSI for the pixel sensors of the CMS tracker.
- 4160 pixels ( $52 \times 80$ ) in  $8 \times 7.6 \text{ mm}^2$  active area.
- Photo counting capable.
- Full pulse processing per pixel.
- Charge threshold of  $1.5 \text{ ke}^-$ , resolution  $\sim 120 \text{ e}^-$ .
- Radiation hardness  $> 2.5 \text{ Mrad}$ .
- Available with Indium bumps for low-T processing as required with CdTe.
- Other chips optional, e.g. RD53a chip.



see: B. Meier 2011 JINST 6 C01011,

D. Hits & A. Starodumov 2015 JINST 10 C05029

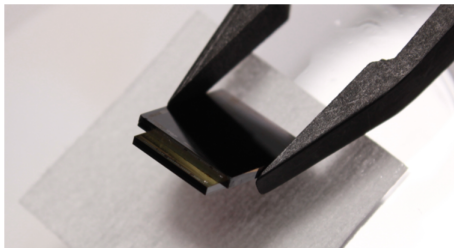
# Prototype Detector

## Prototype

- Ready single detector, successfully bump bonded (Indium).

## Detector readout

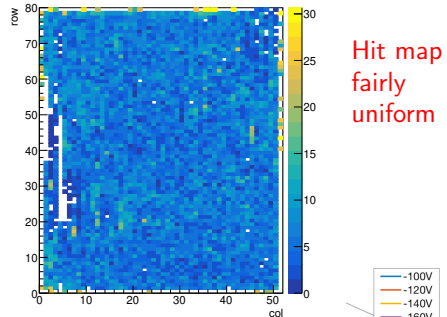
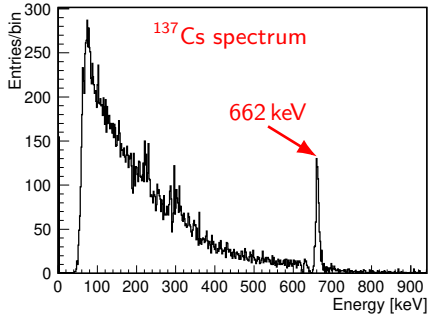
- Currently we use the Detector Test Board (DTB) developed for the PSI46 ROC.
- Features: Altera FPGA, 2x64MB DDR2 RAM, Gigabit Ethernet port, USB 2.0.
- Programmable analog and digital outputs for monitoring.
- Deserializer for 160 MHz and 400 MHz signals.
- Prototype wire bonded to PCB.
- Connected to DTB via passive FEC.



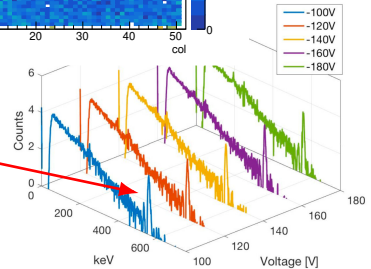
# Results

## Testing the prototype

- First results look promising.
- Good energy resolution ( $< 2\%$ ) for  $^{137}\text{Cs}$  (11.9 keV for the 662 keV gamma emission line).



Detector fully depleted at -100 V



see A. Gädda et al. 2017 JINST 12 C12031



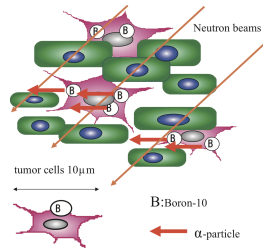
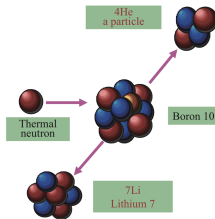
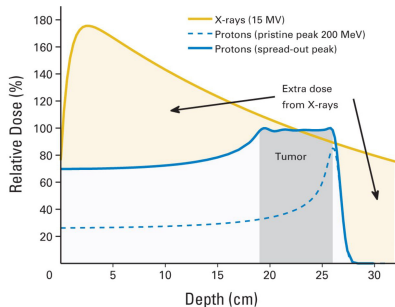
# What are my colleagues doing? For example at Aalto University

Possible application: Imaging detector for Boron Neutron Capture Therapy (BNCT).

Algorithms for BNCT: The probabilistic model.

Well, let's first introduce Boron Neutron Capture Therapy in short.

# Motivation for BNCT



Plot on left from J Clin Oncol. 2014 Sep 10;32(26):2855-63, graphics on right from Kageji et al., JMI 61 3-4 (2014).

# Example of application for our detector

## Boron Neutron Capture Therapy (BNCT)

- Idea of BNCT: Adding  $^{10}\text{B}$  to drug that attaches to cancer cells. Thermal neutron injected to patient captured by  $^{10}\text{B}$ . Violent reaction kills cancer cells ( $^{10}\text{B} + n \rightarrow ^7\text{Li} + \alpha + \gamma$ ).
- PC detectors can shed light on ratio between cancer and healthy cells. Can monitor spatial and temporal development.
- Required for online dosimetry, the last missing piece for full acceptance as alternative radiation therapy.

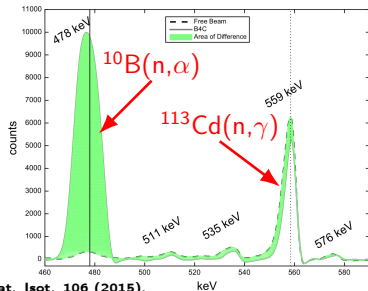
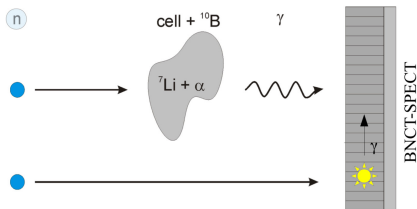
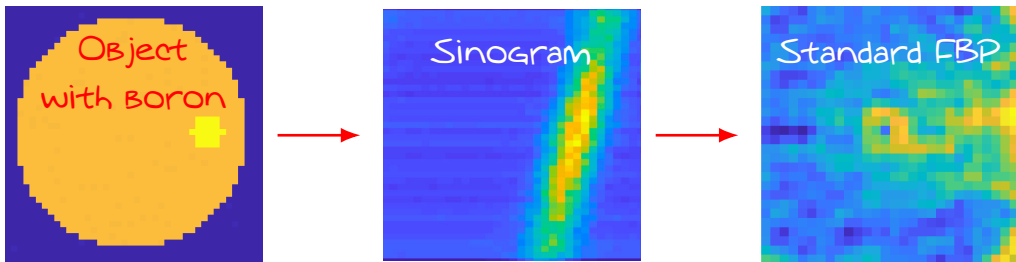


Illustration from Alexander Winkler and Figure from A. Winkler et. al., *Appl. Radiat. Isot.* **106** (2015).

## Challenges

- For imaging we can use direct gammas from BNC or scattered neutrons.
- Neutrons will be caught by  $^{113}\text{Cd}$  and resulting gamma detected (558 keV).
- Problem: we do not have a detector with anti-scatter grid for neutrons.

## Using standard procedure



# At Aalto University

## Algorithms for Boron Neutron Capture Therapy: The probabilistic model

- Measurement of the location of BNC events  $\mathbf{x}^b$  inside sample.
- Signal for each pixel in detector from BNC events

$$\mathbf{y}^b = I_0 A \mathbf{x}^b + \varepsilon,$$

where  $I_0$  is the total number of neutrons,  $A$  a measurement matrix, and the normal distributed measurement noise  $\varepsilon \propto \mathcal{N}(0, \sigma_\varepsilon^2 I)$  with the identity matrix  $I$ .

- Next we introduce Gaussian prior for  $\mathbf{x}^b$ ,

$$p(\mathbf{x}^b) \propto \mathcal{N}(\hat{\mathbf{x}}^b, \sigma_{\mathbf{x}^b}^2 I),$$

where  $\hat{\mathbf{x}}^b$  is the mean of  $\mathbf{x}^b$ .

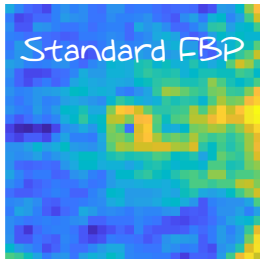
## The probabilistic model

- Now we construct the likelihood function:

$$p(\mathbf{y}^b | \mathbf{x}^b) \propto \mathcal{N}(0, \sigma_\epsilon^2 I)$$

- Then, the posterior distribution has the following form:

$$p(\mathbf{x}^b | \mathbf{y}^b) \propto p(\mathbf{y}^b | \mathbf{x}^b)p(\mathbf{x}^b)$$





# BNCT facility

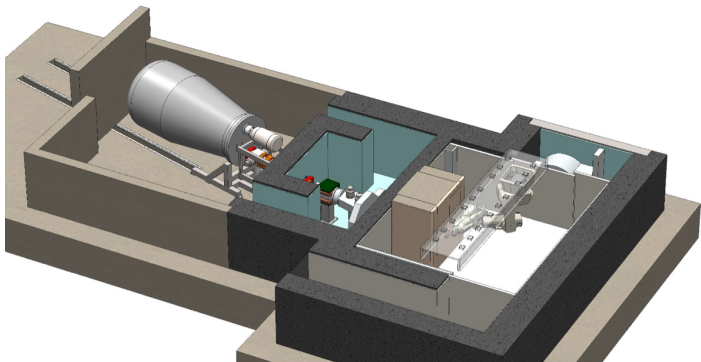
## BNCT setup

Currently a BNCT facility is being built at the Helsinki University Hospital in collaboration with Neutron Therapeutics.

- 2.6 MV / 30 mA Proton Accelerator.
- Neutron generating target.
- Beam Shaping Assembly.
- Moving table for positioning.

Accelerator in accreditation phase by radiation safety authority. Clinical trials start 2020.

Test of detector array under real conditions. Key interest: 478 keV gamma-ray from BNC reactions.





# Conclusions and outlook

## Achievements

- CdTe pixel detector prototypes successfully manufactured and tested.
- Started production of new CdTe detectors for detector array.
- Algorithms for localizing BNCT events advancing.

## Next

- Building detector array based on PSI46dig ROC.
- Preparing for testing array in radiation beams i.e. in the BNCT facilities of the nearby University hospital.